

November 2013



# FCI25N60N N-Channel SupreMOS<sup>®</sup> MOSFET 600 V, 25 A, 125 mΩ

### Features

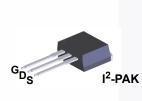
- R<sub>DS(on)</sub> = 107 mΩ (Typ.) @ V<sub>GS</sub> = 10 V, I<sub>D</sub> = 12.5 A
- Ultra Low Gate Charge (Typ. Q<sub>g</sub> = 57 nC)
- Low Effective Output Capacitance (Typ. C<sub>oss(eff.)</sub> = 262 pF)
- 100% Avalanche Tested
- RoHS Compliant

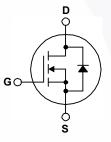
### Application

- Solar Inverter
- AC-DC Power Supply

## Description

The SupreMOS<sup>®</sup> MOSFET is Fairchild Semiconductor's next generation of high voltage super-junction (SJ) technology employing a deep trench filling process that differentiates it from the conventional SJ MOSFETs. This advanced technology and precise process control provides lowest Rsp on-resistance, superior switching performance and ruggedness. SupreMOS MOSFET is suitable for high frequency switching power converter applications such as PFC, server/telecom power, FPD TV power, ATX power, and industrial power applications.





### MOSFET Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted.

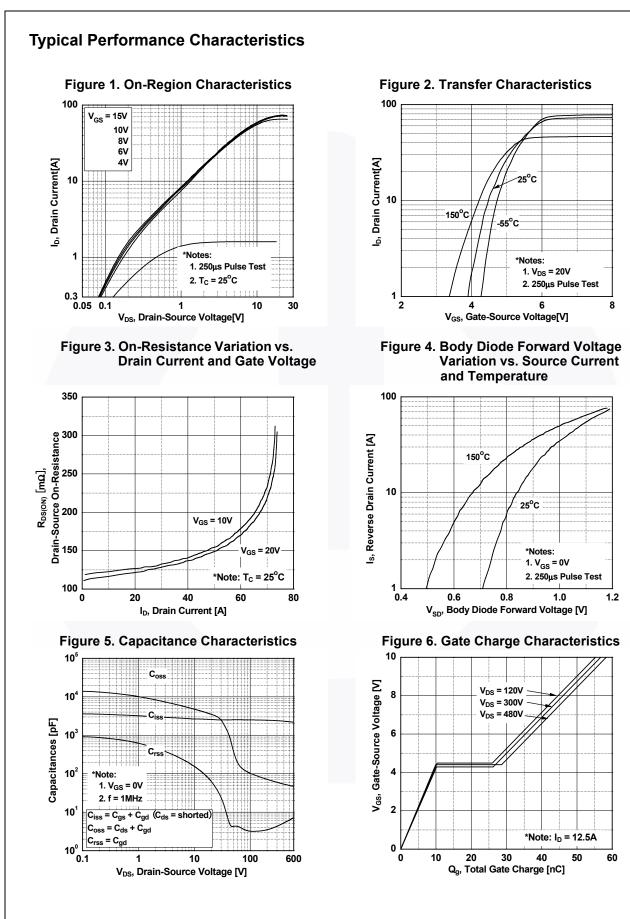
Symbol	Parameter			FCI25N60N_F102	Unit	
V <sub>DSS</sub>	Drain to Source Voltage			600	V	
V <sub>GSS</sub>	Gate to Source Voltage			±30	V	
I <sub>D</sub>	Drain Current	- Continuous (T <sub>C</sub> = 25 <sup>o</sup> C)		25	A	
		- Continuous (T <sub>C</sub> = 100 <sup>o</sup> C)		16		
I <sub>DM</sub>	Drain Current	- Pulsed (N	Note 1)	75	А	
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 2)			861	mJ	
I <sub>AR</sub>	Avalanche Current (Note 1)			8.3	А	
E <sub>AR</sub>	Repetitive Avalanche Energy		Note 1)	2.2	mJ	
dv/dt	MOSFET dv/dt			100	V/ns	
	Peak Diode Recovery dv/	15				
P <sub>D</sub>	Power Dissipation	$(T_{\rm C} = 25^{\rm o}{\rm C})$		216	W	
		- Derate Above 25°C		1.72	W/ºC	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range			-55 to +150	°C	
TL	Maximum Lead Temperat	ture for Soldering, 1/8" from Case for 5 Secon	ds	300	°C	

### **Thermal Characteristics**

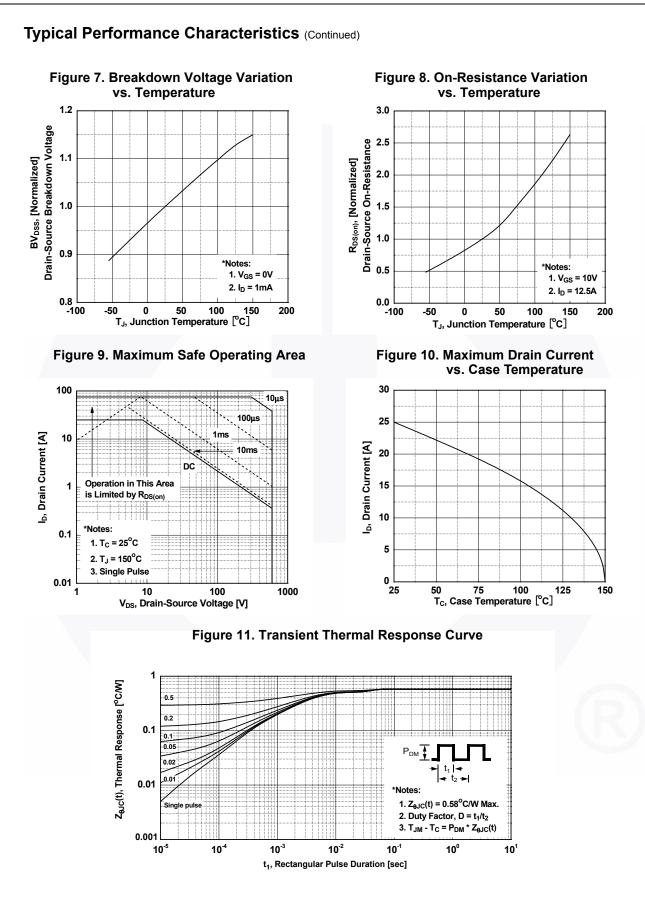
Symbol	Parameter	FCI25N60N_F102	Unit	
$R_{ extsf{ heta}JC}$	θJC Thermal Resistance, Junction to Case, Max.		°C/W	
$R_{\thetaJA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	0/00	

Part Nun	Part Number Top Mark Pa		Package	Packing Meth	od Reel Size	Тар	e Width	Qua	ntity	
FCI25N60N	L_F102	FCI25N60N	I <sup>2</sup> -PAK	Tube	N/A		N/A		50 units	
Electrica	l Char	acteristics T <sub>c</sub> =:	250C upload	othonwice noted	<b>I</b>			1		
Symbol		Parameter	25°C unless	Test Con	ditions	Min.	Тур.	Max.	Uni	
Off Charac	toristics						.,,,,,	maxi	•	
			taga	1 = 1 = 0	$V = 25^{\circ}C$	600	-	-	V	
BV <sub>DSS</sub> ΔBV <sub>DSS</sub>	Drain to Source Breakdown Voltage Breakdown Voltage Temperature		•	$I_{\rm D}$ = 1 mA, $V_{\rm GS}$ = 0 V, $T_{\rm J}$ = 25°C		000	-	-		
$/\Delta T_J$	Coefficie			$I_D = 1 \text{ mA}$ , Referenced to $25^{\circ}$ C		-	0.74	-	V/ºC	
I <sub>DSS</sub>	Zero Ga	ro Gate Voltage Drain Current		V <sub>DS</sub> = 480 V, V <sub>GS</sub> = 0 V		-	-	10	μA	
033		5		V <sub>DS</sub> = 480 V, T <sub>J</sub> = 1		-	-	100	· ·	
I <sub>GSS</sub>	Gate to	Body Leakage Current		$V_{GS} = \pm 30 \text{ V}, \text{ V}_{DS} =$	= 0 V	-	-	±100	nA	
On Charac	teristics	;								
V <sub>GS(th)</sub>	Gate Th	reshold Voltage		V <sub>GS</sub> = V <sub>DS</sub> , I <sub>D</sub> = 25	0 μΑ	2.0	-	4.0	V	
R <sub>DS(on)</sub>	Static Dr	ain to Source On Resis	tance	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 12	2.5 A	-	0.107	0.125	Ω	
9 <sub>FS</sub>	Forward	Transconductance		V <sub>DS</sub> = 20 V, I <sub>D</sub> = 12	2.5 A	-		-	S	
Dynamic C	haracte	ristics								
C <sub>iss</sub>		pacitance					2520	3352	pF	
C <sub>oss</sub>		Capacitance		V <sub>DS</sub> = 100 V, V <sub>GS</sub> =	= 0 V,	_	103	137	pF	
C <sub>rss</sub>		Transfer Capacitance		f = 1 MHz		_	3.2	5	pF	
C <sub>oss</sub>		Capacitance		V <sub>DS</sub> = 380 V, V <sub>GS</sub> :	= 0 V. f = 1 MHz	-	55	-	pF	
C <sub>oss(eff.)</sub>		ective Output Capacitance		$V_{\rm DS} = 0 \text{ V to } 480 \text{ V}, \text{ V}_{\rm GS} = 0 \text{ V}$		-	262	_	pF	
Q <sub>g(tot)</sub>		te Charge at 10V					57	74	nC	
Q <sub>gs</sub>		Source Gate Charge		V <sub>DS</sub> = 380 V, I <sub>D</sub> = 12.5 A, V <sub>GS</sub> = 10 V (Note 4)		-	10	-	nC	
Q <sub>gd</sub>	Gate to I	Drain "Miller" Charge				-	18	-	nC	
ESR	Equivale	nt Series Resistance (C	G-S)	f = 1 MHz		-	1	-	Ω	
Switching	Charact	eristics								
•		Delay Time					21	52	ns	
t <sub>d(on)</sub>		Rise Time		V <sub>DD</sub> = 380 V, I <sub>D</sub> = 12.5 A, V <sub>GS</sub> = 10 V, R <sub>G</sub> = 4.7 Ω			21	54	ns	
t <sub>r</sub>		Delay Time				-7-	68	146	ns	
t <sub>d(off)</sub> t <sub>f</sub>		Fall Time			(Note 4)	-	5	20	ns	
					(1010 4)		U	20	110	
		e Characteristics	. <u> </u>	<u> </u>				0.5		
l <sub>s</sub>		n Continuous Drain to S				-	-	25	A	
I <sub>SM</sub>		n Pulsed Drain to Sourc Source Diode Forward '			E A	-	-	75	A V	
V <sub>SD</sub>			J	$V_{GS} = 0 V, I_{SD} = 12$		-	-	1.2	-	
t <sub>rr</sub>		Recovery Time Recovery Charge		V <sub>GS</sub> = 0 V, I <sub>SD</sub> = 12 dI <sub>F</sub> /dt = 100 A/μs	5 A,	-	370 7	-	ns µC	
Q <sub>rr</sub> lotes:	Reverse						I		μΟ	
	= 25 Ω, starting	imited by maximum junction ter g T <sub>J</sub> = 25°C. <sub>DD</sub> $\leq$ 380 V, starting T <sub>J</sub> = 25°C.	nperature.							

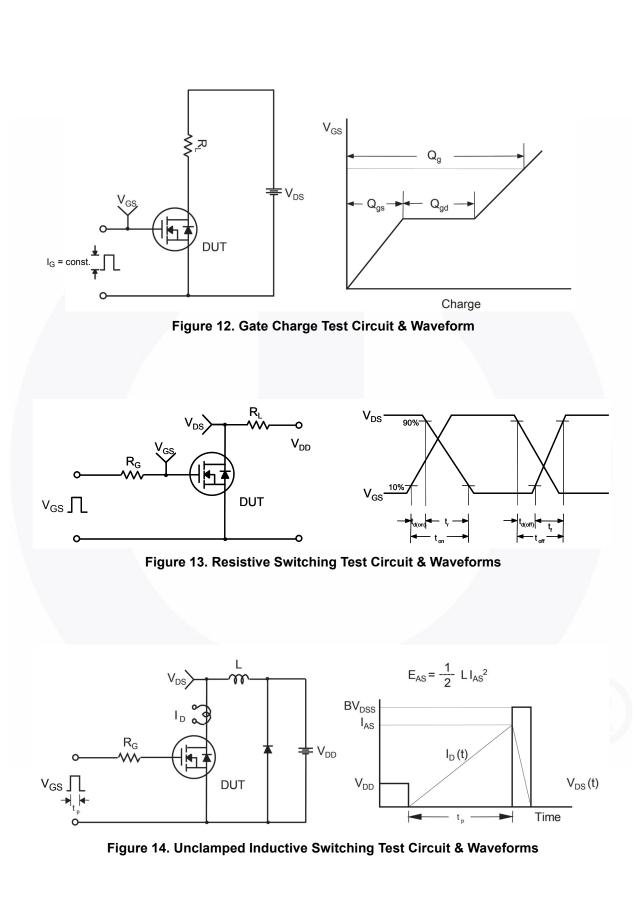
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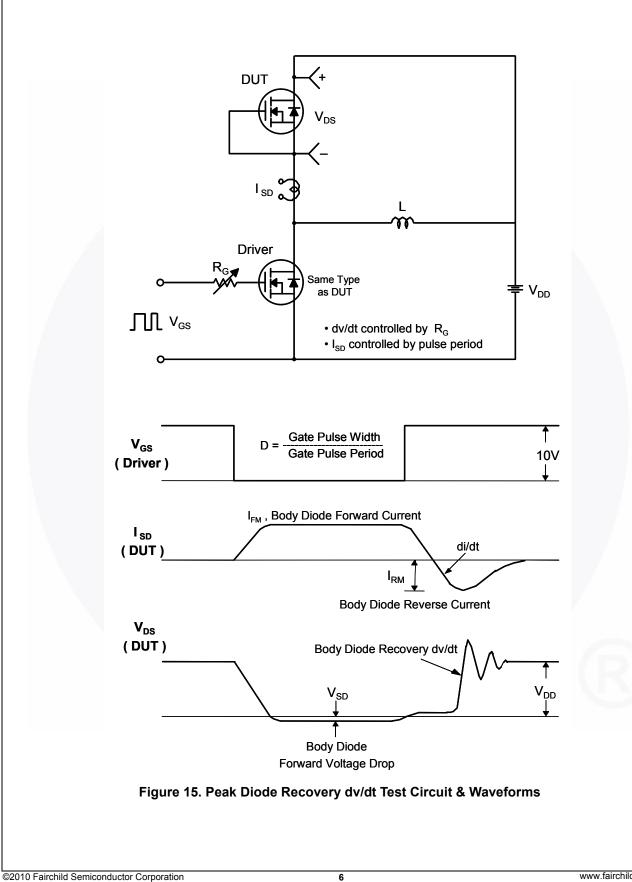


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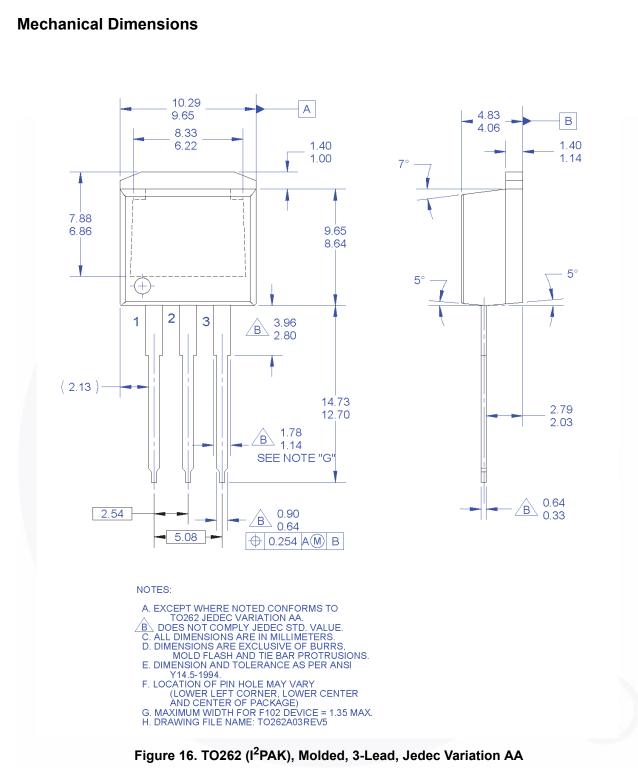


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